

RoHS Compliant Product  
A suffix of "-C" specifies halogen free

**FEATURES**

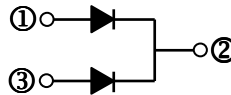
- Planar MOS Schottky technology
- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

**MECHANICAL DATA**

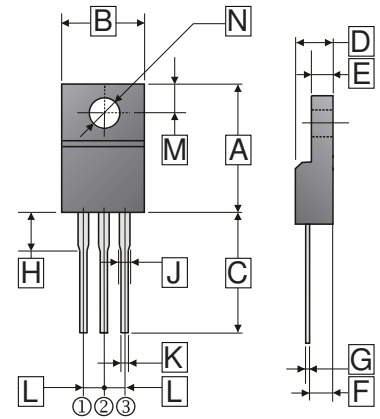
- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Lead solderable per MIL-STD-202 method 208 guaranteed
- Polarity: As Marked
- Mounting position: Any

**ORDER INFORMATION**

Part Number	Type
SBL20A60F	Lead (Pb)-free
SBL20A60F-C	Lead (Pb)-free and Halogen-free



**ITO-220**



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	14.50	16.50	H	2.70	4.35
B	9.50	10.72	J	0.90	1.70
C	12.60	14.22	K	0.30	0.95
D	4.20	5.10	L	2.34	2.75
E	2.30	3.30	M	2.40	3.60
F	2.30	3.10	N	∅ 3.0	∅ 3.8
G	0.30	0.75			

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load.  
For capacitive load, de-rate current by 20%.)

Parameter	Symbol	Ratings	Unit
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	60	V
Working Peak Reverse Voltage	$V_{RSM}$	60	V
Maximum DC Blocking Voltage	$V_{DC}$	60	V
Maximum Average Forward Rectified Current	(Per Leg)	10	A
	(Per Device)	20	
Peak Forward Surge Current, 8.3ms single half sine-wave Superimposed on rated load (JEDEC method)	$I_{FSM}$	120	A
Voltage Rate of Change (Rated $V_R$ )	dv/dt	10000	V/ $\mu$ s
Typical Thermal Resistance	$R_{\theta JC}$	4	°C/W
Operating and Storage Temperature Range	$T_J, T_{STG}$	150, -55~150	°C

**ELECTRICAL CHARACTERISTICS**

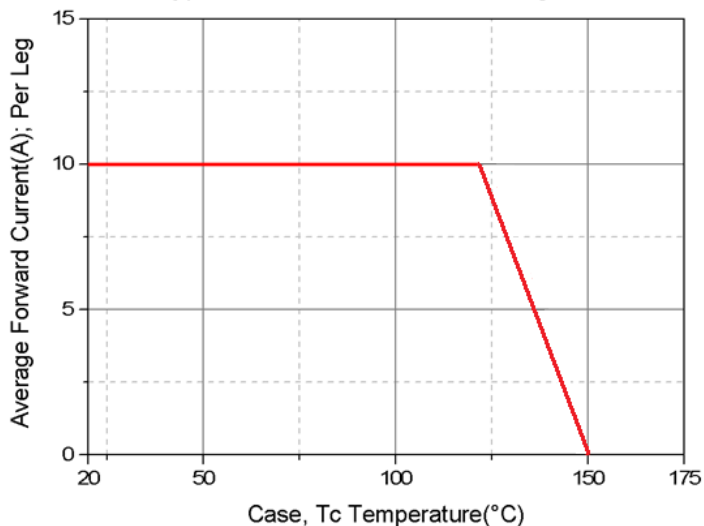
Parameter	Symbol	Typ.	Max.	Unit	Test Conditions
Maximum Instantaneous Forward Voltage	$V_F$	0.45	0.49	V	$I_F=3A, T_J=25^\circ C$
		0.5	0.55		$I_F=5A, T_J=25^\circ C$
		0.6	0.65		$I_F=10A, T_J=25^\circ C$
		0.57	-		$I_F=10A, T_J=125^\circ C$
Maximum DC Reverse Current @Rated DC Blocking Voltage <sup>2</sup>	$I_R$	-	0.5	mA	$T_J=25^\circ C$
		-	20		$T_J=100^\circ C$
Typical Junction Capacitance <sup>1</sup>	$C_J$	280	-	pF	

Notes:

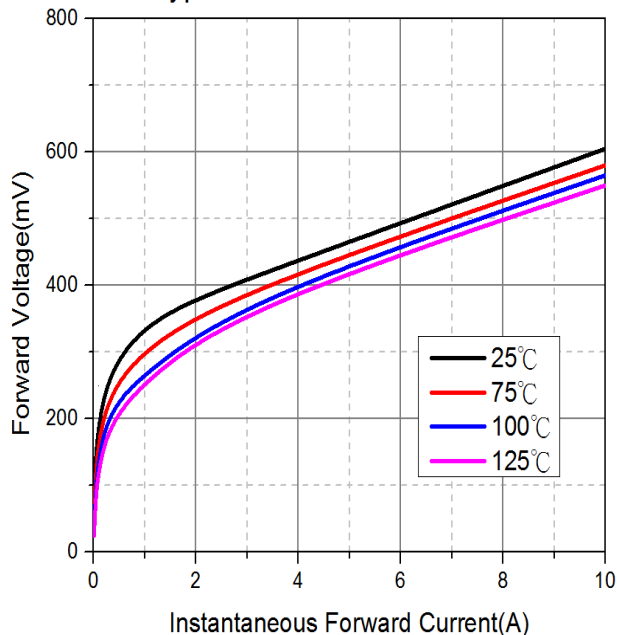
1. Measured at 1MHz and applied reverse voltage of 4V D.C.
2. Pulse Test: Pulse Width=300 $\mu$ s, Duty Cycle  $\leq$  2%.

**RATINGS AND CHARACTERISTIC CURVES**

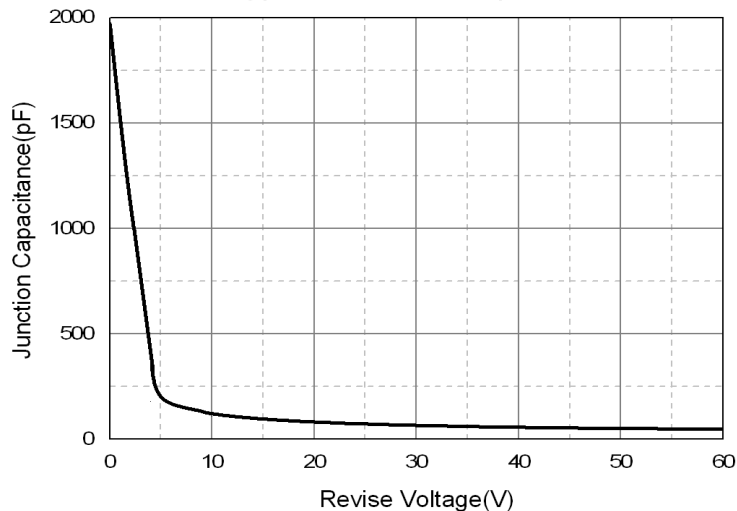
Typical Forward Current Derating Curve



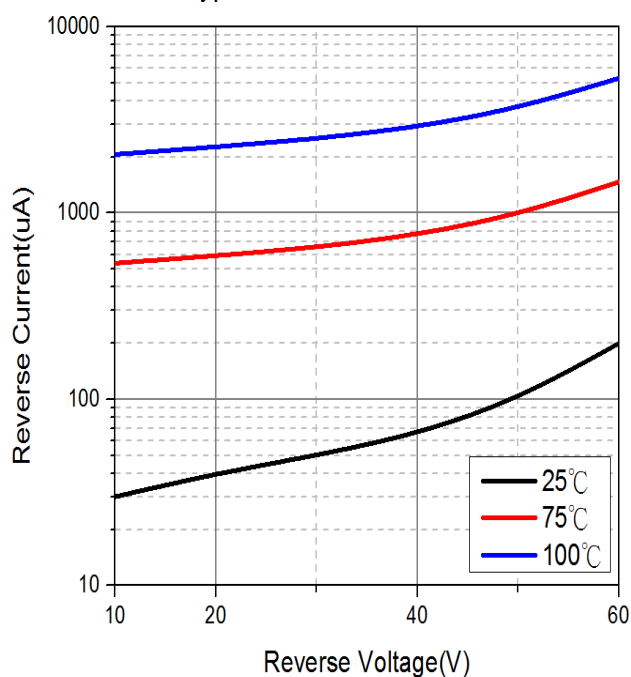
Typical Forward Characteristic



Typical Junction Capacitance



Typical Reverse Characteristic



Maximum Non-Repetitive Forward Surge Current

